NSN 5961-01-135-2073

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View Online at https://aerobasegroup.com/nsn/5961-01-135-2073

view Online at https://aerobasegroup.com/hsh/5961-01-135-2073
Inclosure Material:
Metal
Overall Length:
1.573 inches
Overall Height:
Between 0.250 inches and 0.450 inches
Overall Width:
1.050 inches
End Application:
1270-01-122-5234 18876
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-3
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case and quality assurance level tx
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
120.0 breakdown voltage, collector-to-base, emitter open and 90.0 breakdown voltage, collector-to-emitter, base open and 7.0
breakdown voltage, emitter-to-base, collector open
Current Rating Per Characteristic:
Between 10.00 amperes source cutoff current and 50.00 amperes source cutoff current
Power Rating Per Characteristic:
140.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
1 case and 2 pin

Shelf Life:

NI/o

Specification Data:

81349-mil-s-19500/528 government specification

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Demilitarization:

No

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